

(E1)

$$\vec{v}_0 = 0$$

$$|\vec{E}| = 640 \text{ N/C}$$

$$|\vec{v}(t)| = 1.2 \cdot 10^6 \text{ m/s}$$

(a) + ?

The proton is accelerated due to  $\vec{F}_e = e\vec{E} \Rightarrow$

$\Rightarrow$  Using the 2nd Newton's Law:

$$eE = ma \rightarrow a = \frac{eE}{m} = \frac{1.6 \cdot 10^{-19} \cdot 640}{1.67 \cdot 10^{-27}} \text{ (m/s}^2\text{)} =$$

$$= 6.13 \cdot 10^{10} \text{ m/s}^2$$

As the force is uniform, the acceleration is uniform too  $\Rightarrow$  motion with uniform acc:

$$\vec{r} = \cancel{\vec{r}_0} + \cancel{\vec{v}_0}t + \frac{1}{2}\vec{a}t^2 ; \quad \vec{v}(t) = \cancel{\vec{v}_0} + \vec{a}t$$

Supposing for example that the direction of  $\vec{E}$  is along the x-axis, then:

$$x = \frac{1}{2}at^2 ; v(t) = at$$

From the 2nd equation we can derive "t":  $v(t) = 1.2 \cdot 10^6 \text{ m/s} = 6.13 \cdot 10^{10} \frac{\text{m}}{\text{s}^2} \cdot t$

$$\rightarrow \boxed{t = 1.96 \cdot 10^{-5} \text{ s}}$$

(b) x 2. Using the 1st equation:

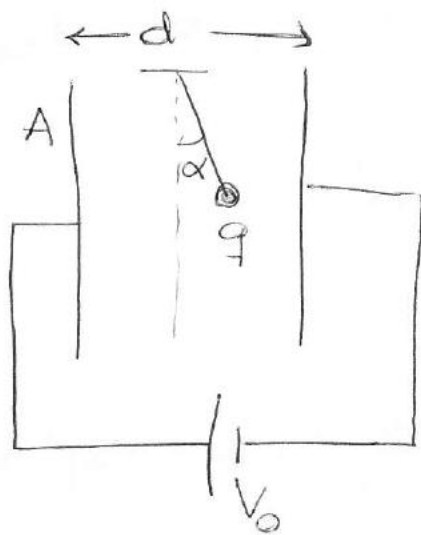
$$\boxed{x = \frac{1}{2} a t^2 = 11.77 \text{ m}}$$

$$(c) \quad K = \frac{1}{2} m v^2 = 1.2 \cdot 10^{-15} \text{ J} \quad \begin{matrix} \uparrow & \downarrow \\ 1 \text{ eV} = 1.6 \cdot 10^{-19} \text{ J} & = 7515 \text{ eV} \end{matrix}$$

$$v(t) = 1.2 \cdot 10^6 \text{ m/s}$$

$$m_p = 1.67 \cdot 10^{-27} \text{ kg}$$

E2



(a)  $d, E, Q$

$$C = \epsilon_0 \frac{A}{d} = \epsilon_0 \cdot \frac{1.13 \text{ m}^2}{0.04 \text{ m}} = 2.5 \cdot 10^{-10} \text{ F} = 250 \text{ pF}$$

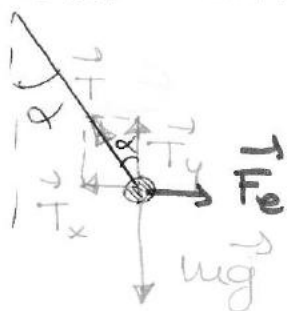
$$V_0 = E \cdot d \rightarrow E = \frac{V_0}{d} = \frac{500 \text{ V}}{0.04 \text{ m}} = 12.5 \cdot 10^3 \text{ V/m}$$

$$Q = C \cdot V_0 = 125 \text{ nC}$$

(b) The pendulum is in equilibrium; let us draw the forces acting on the system:

$$|\vec{T}_x| = T \sin \alpha$$

$$|\vec{T}_y| = T \cos \alpha$$



$\Rightarrow$  In principle, we do not know if

$\vec{F}_e$  is directed along this or the opposite direction, as we do not know the sign of  $q$ . However, in order to have an equilibrium of forces,  $\vec{F}_e$  must be directed

along the direction indicated, so that:

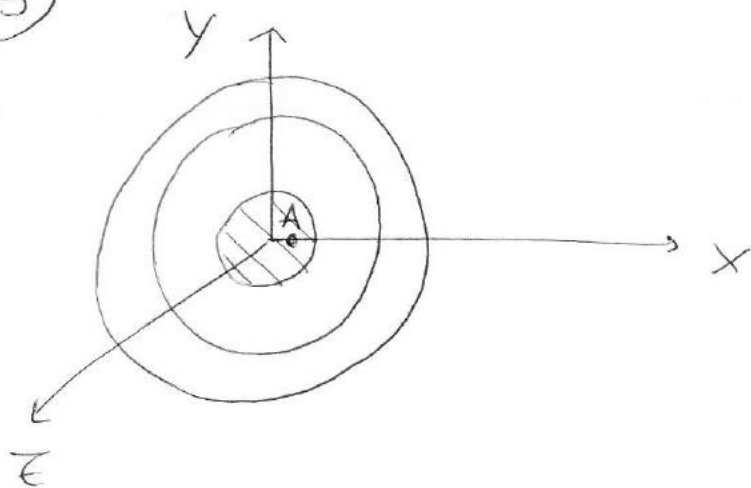
$$\vec{T}_x = \vec{F}_e \quad \text{and} \quad \vec{T}_y = m\vec{g}$$

$$T \cos \alpha = mg \rightarrow T = \frac{mg}{\cos \alpha}$$

$$T \sin \alpha = qE \rightarrow qE = \frac{mg}{\cos \alpha} \sin \alpha = mg \tan \alpha ;$$

$$q = \frac{mg}{E} \tan \alpha = \frac{2 \cdot 10^{-3} \text{ kg} \cdot 9,81 \text{ m/s}^2}{12,5 \cdot 10^3 \text{ N/C}} \tan 30^\circ = 0,9 \mu\text{C}$$

E3

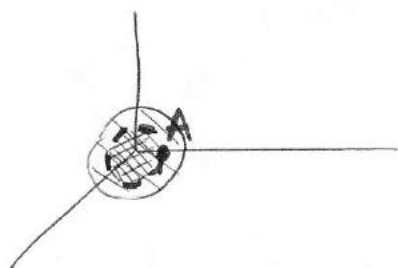
solid sphere,  $R_1$ ,  $\rho_0$ metallic shell,  $R_2$ ,  $R_3$ ,  $Q$ 

$$R_1 = 0.1 \text{ m}$$

$$R_2 = 0.3 \text{ m}$$

$$R_3 = 0.4 \text{ m}$$

A (5, 0, 0) cm  $\rightarrow$  Inside the solid sphere.



We draw a gaussian surface passing through A. Only the charge inside that surface

will contribute to  $\vec{E}$ .

$$Q_{\text{ins}} = \rho_0 \cdot V_{\text{ins}} = \rho_0 \cdot \frac{4}{3} \pi r^3 ; r = 0.05 \text{ m}$$

$$\oint \vec{E} \cdot d\vec{S} = \frac{Q_{\text{ins}}}{\epsilon_0} \rightarrow \oint \vec{E} \cdot d\vec{S} = E \cdot \oint dS = E \cdot 4\pi r^2$$

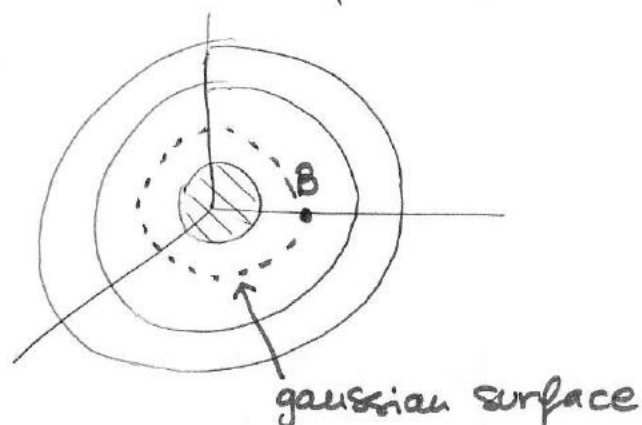
$$E \cdot 4\pi r^2 = \frac{1}{\epsilon_0} \cdot \rho_0 \cdot \frac{4}{3} \pi r^3 \rightarrow \vec{E} = \frac{\rho_0 r}{3\epsilon_0} \vec{e}_x$$

$\rho_0 < 0$  so finally,  $\vec{E} = |\vec{E}|(-\vec{e}_x)$

$$\vec{E} = \frac{-4.8 \cdot 10^{-3} \cdot 0.05}{3\epsilon_0} \vec{e}_x = -90.4 \cdot 10^5 \vec{e}_x \left( \frac{\text{N}}{\text{C}} \right)$$

B (20, 0, 0) cm

$r = 0.2 \text{ m} \rightarrow$  This point is located between the two spheres.



$$\oint \vec{E} \cdot d\vec{S} = \frac{Q_{\text{ins}}}{\epsilon_0} ; \quad \begin{aligned} &\oint \vec{E} \cdot d\vec{S} = E \cdot 4\pi r^2 \\ &\rightarrow Q_{\text{ins}} = \rho_0 \cdot \frac{4}{3} \pi R_1^3 \end{aligned}$$

$$E \cdot 4\pi r^2 = \frac{\rho_0 \cdot \frac{4}{3} \pi R_1^3}{\epsilon_0} \rightarrow E = \frac{\rho_0 R_1^3}{3\epsilon_0 r^2} \vec{e}_x$$

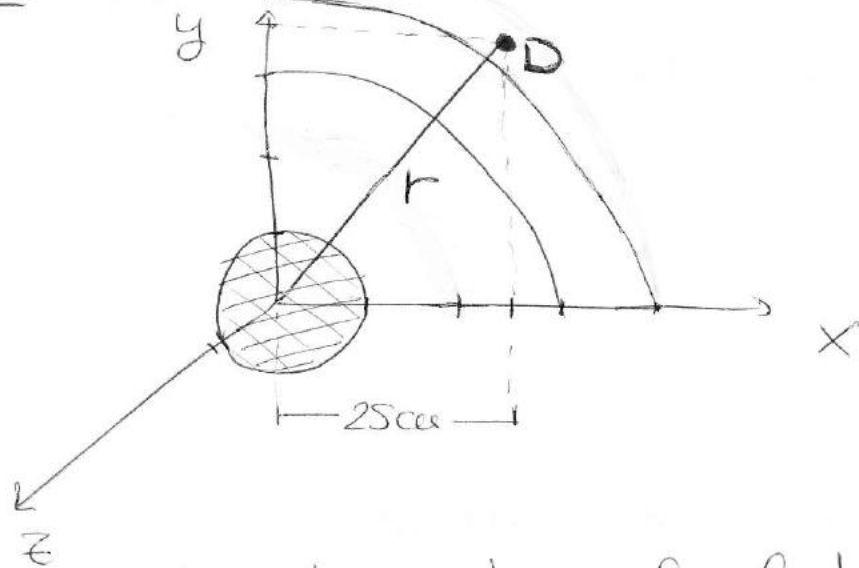
$$\vec{E} = - \frac{4.8 \cdot 10^{-3} \cdot (0.1)^3}{3 \epsilon_0 (0.2)^2} \vec{e}_x = -45 \cdot 10^5 \vec{e}_x \text{ (N/C)}$$

C (38, 0, 0) cm

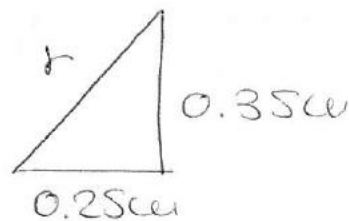
$r = 0.38 \text{ m} \rightarrow$  This point is located inside the metallic sphere.

$$\vec{E} = 0 \text{ (conductor)}$$

D (25, 35, 0) cm



We have to calculate the distance to D:



$$r = \sqrt{0.35^2 + 0.25^2} =$$

$$= 0.43 \text{ m} \Rightarrow$$

$\Rightarrow$  Point D is external to all spheres.

$$\oint \vec{E} \cdot d\vec{S} = \frac{Q_{\text{ins}}}{\epsilon_0}$$

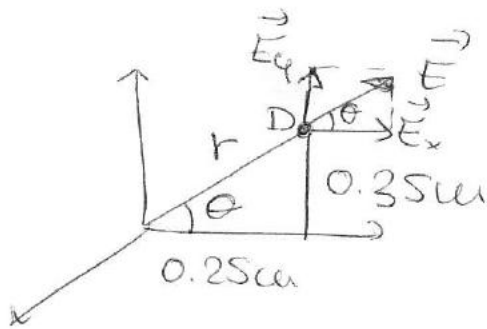
$$Q_{\text{ins}} = \left[ \epsilon_0 \cdot \frac{4}{3} \pi R_1^3 + Q \right] = \left[ -4.8 \cdot 10^{-3} \frac{4}{3} \pi (0.1)^3 + \right.$$

all the charge

$$\left. + 30 \cdot 10^{-6} \right] = -2.01 \cdot 10^{-5} + 30 \cdot 10^{-6} = 9.89 \cdot 10^{-6} \text{ C}$$

$$E \cdot 4\pi (0.43)^2 = \frac{9.89 \cdot 10^{-6} \text{ C}}{\epsilon_0} \rightarrow \vec{E} = 4.8 \cdot 10^5 \vec{e}_r \left( \frac{\text{N}}{\text{C}} \right)$$

However, we have to express this in rectangular coordinates, so:



$$\tan \theta = \frac{0.35}{0.25} = 1.4 \rightarrow \theta = 54.46^\circ$$

$$\vec{E} = \vec{E}_x + \vec{E}_y = |\vec{E}| \cdot \overbrace{\cos \theta}^{0.58} \vec{e}_x + |\vec{E}| \cdot \overbrace{\sin \theta}^{0.81} \vec{e}_y$$

$$\vec{E} = 4.8 \cdot 10^5 (0.58 \vec{e}_x + 0.81 \vec{e}_y) =$$

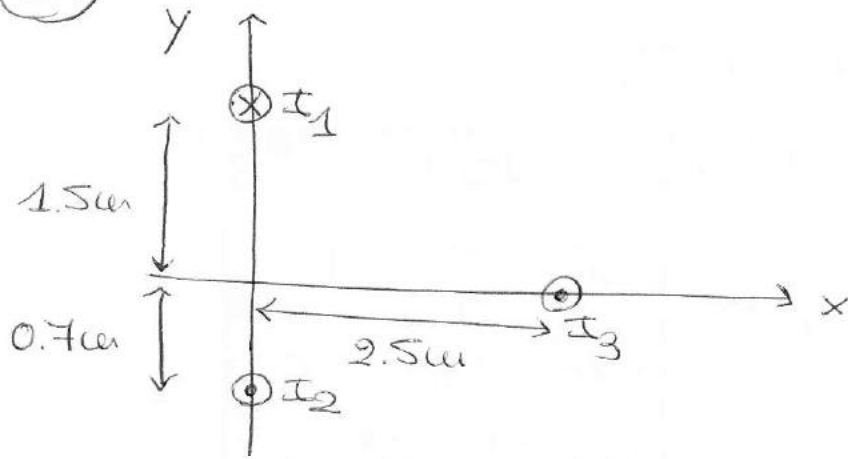
$$= (2.79 \vec{e}_x + 3.9 \vec{e}_y) \cdot 10^5 (\text{N/C})$$

Or, alternatively:  $\vec{E} = |\vec{E}| \cdot \vec{u}$ , where:

$$\vec{u} = \frac{\vec{r}}{|\vec{r}|} = \frac{(0.25, 0.35, 0)}{0.43} \rightarrow \text{unit vector in the direction of the field.}$$



E4



$$I_1 = 2\text{A}$$

$$I_2 = 5\text{A}$$

$$I_3 = 10\text{A}$$

$$(a) \quad \vec{B}(0,0,0) = \vec{B}_1(0,0,0) + \vec{B}_2(0,0,0) + \vec{B}_3(0,0,0)$$

Infinite wires  $\rightarrow$  We can apply Ampère's Law:

$$\oint_C \vec{B} \cdot d\vec{\ell} = \mu_0 I_c \rightarrow B \cdot 2\pi r = \mu_0 I_c$$

$$\boxed{\vec{B}_1} \quad B_1 \cdot 2\pi(1.5) = \mu_0 \cdot I_1 \rightarrow \vec{B}_1 = \frac{4\pi \cdot 10^{-7} \cdot 2}{2\pi \cdot (1.5)} (-\vec{e}_x)$$

$$\vec{B}_1 = 2.67 \cdot 10^{-7} (-\vec{e}_x) \text{ T}$$

$$\boxed{\vec{B}_2} \quad B_2 \cdot 2\pi(0.7) = \mu_0 I_2 \rightarrow \vec{B}_2 = \frac{4\pi \cdot 10^{-7} \cdot 5}{2\pi \cdot (0.7)} (-\vec{e}_x)$$

$$\vec{B}_2 = 14.29 \cdot 10^{-7} (-\vec{e}_x) \text{ T}$$

$$\boxed{\vec{B}_3} \quad B_3 \cdot 2\pi(2.5) = \mu_0 I_3 \rightarrow \vec{B}_3 = \frac{4\pi \cdot 10^{-7} \cdot 10}{2\pi \cdot (2.5)} (-\vec{e}_y)$$

$$\vec{B}_3 = 8 \cdot 10^{-7} (-\vec{e}_y) \text{ T}$$

$$\text{So: } \vec{B}(0,0,0) = (-16.96 \vec{e}_x - 8 \vec{e}_y) \cdot 10^{-7} \text{ T}$$

(b)

electron  $\rightarrow q_e = -1.6 \cdot 10^{-19} \text{ C}$

$$\vec{v}_e = 3 \cdot 10^4 \vec{e}_x + 5 \cdot 10^4 \vec{e}_y \text{ (m/s)}$$

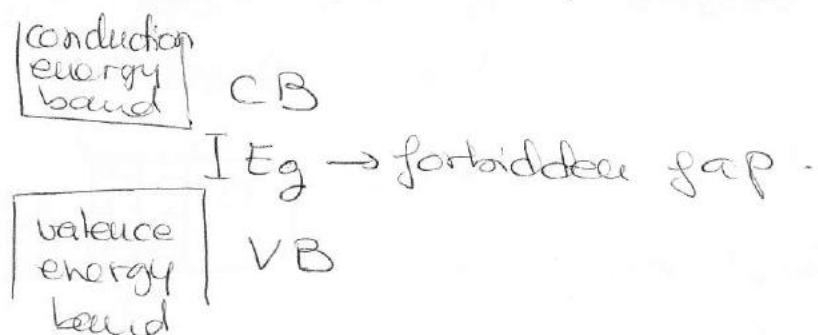
$$\vec{F} = q \vec{v} \times \vec{B} = -1.6 \cdot 10^{-19} \cdot \begin{vmatrix} \vec{i} & \vec{j} & \vec{k} \\ 3 \cdot 10^4 & 5 \cdot 10^4 & 0 \\ -16.96 \cdot 10^{-7} & -8 \cdot 10^{-7} & 0 \end{vmatrix} =$$

$$= 1.6 \cdot 10^{-19} \cdot 10^4 \cdot 10^{-7} \begin{vmatrix} \vec{i} & \vec{j} & \vec{k} \\ 3 & 5 & 0 \\ 16.96 & 8 & 0 \end{vmatrix} =$$

$$= \underline{\underline{-97.3 \cdot 10^{-22} \vec{k} \text{ (N)}}}$$

Q1

In a semiconductor, the valence band (last band filled with  $e^-$ ) and the conduction band (next band, where  $e^-$  can move freely, thus contributing to conductivity) are separated by a small ( $\sim 1\text{eV}$ ) forbidden energy gap:



At  $T=0\text{K}$ , the solid is frozen and all valence  $e^-$  are participating in covalent bonds (no free  $e^-$ ). Thinking in terms of band theory, this means that all  $e^-$  are on the VB, being the CB empty.

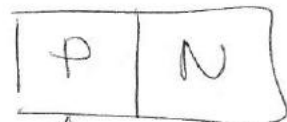
At  $T>0\text{K}$ , the lattice is vibrating some bonds break, so those  $e^-$  are now free to move. In terms of band theory, this means that some  $e^-$  in the VB have received enough thermal energy to be able to jump through  $E_g$  onto the CB, being now free to contribute to conduction.

As  $T \uparrow$  more and more, more  $e^-$  will jump through  $E_g$  and the conductivity  $\uparrow$ .

[Q2]

A semiconductor diode is based on the PN junction.

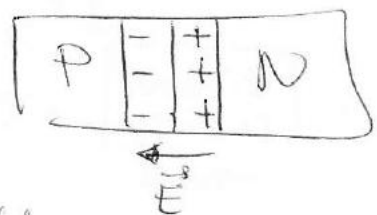
When we have a PN junction:



There is 1st diffusion of holes towards the N-side and  $e^-$  " " P-side.

more holes than  $e^-$  on P-side  
more  $e^-$  than holes on N-side

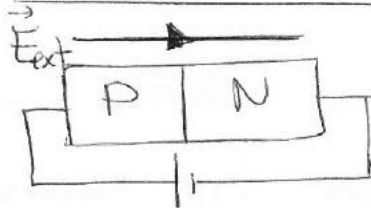
This induces the creation of a region near the junction depleted in free charges (depletion region):



An  $E_s$  is created on this region. It balances diffusion, and equilibrium is reached.

If we apply an external voltage, two situations can arise:

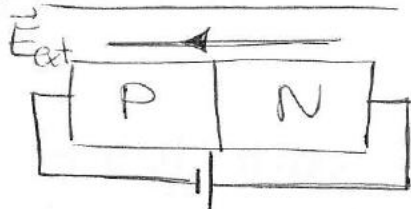
① Forward bias: { P-side connected to  $\oplus$  terminal  
N- " " "  $\ominus$  "



As a consequence, the external  $E$  makes charge carriers to move

through the junction, and the width of the depletion region decreases. In this situation, there is a high current passing through. The  $I \uparrow$  as  $V \uparrow$  (right side of the curve).

② Reverse bias: { P-side connected to  $\ominus$  terminal  
N-side " " "  $\oplus$  terminal



In this case,  $E_{ext}$  pushes  $e^-$  and holes away from the junction, and the width of the depletion region increases too. In this case, there is nearly no current passing through (left side of the curve).